NSN 5961-00-836-9820



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-836-9820 **Inclosure Material:** Metal **Overall Length:** 0.310 inches **Overall Diameter:** 0.687 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.0 emitter to base voltage, static, collector open and 80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage, dc with base short-circuited to emitter and 60.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 1.20 amperes source cutoff current and 0.40 amperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 99971-7618131 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: